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## Roll-to-roll continuous carbon nanotube sheets with high electrical conductivity

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Large scale manufacturing of electrically conductive carbon nanotube (CNT) sheets with production capability, low cost, and long-term electrical performance stability is still a challenge. A new method to fabricate highly conductive continuous buckypaper (CBP) with roll-to-roll production capability and relatively low cost is reported. The electrical conductivity of CBP can be improved to  $7.6 \times 10^4 \text{ S m}^{-1}$  by using an oxidant chemical (*i.e.*  $\text{HNO}_3$  and  $\text{I}_2$ ) doping method. To compensate for the conductivity degradation caused by the instability of the oxidant chemical doping, a polymer layer of poly(3,4-ethylenedioxythiophene)-poly(styrenesulfonate) (PEDOT:PSS) was coated on the chemically doped CBP. The fabricated highly conductive CBP showed stable electrical performance in air for more than a month. This CBP material with high electrical conductivity, relatively low cost, and roll-to-roll manufacturing capability could enable a wide range of engineering applications including flexible conductors, electromagnetic interference (EMI) shielding materials, and electrodes in energy devices.

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## Introduction

Since the discovery of carbon nanotubes (CNTs) in 1991 by Sumio Iijima,<sup>1</sup> many scientists became interested in their high electrical conductivity and potential applications. With the electrical conductivity of an individual nanotube reaching up to  $10^8 \text{ S m}^{-1}$ , CNTs are comparable to that of copper<sup>2</sup> but with only 1/6 of its density. Even today, we have seen explorations of using CNT wires in transformer and motor demonstrations, and other electrical applications in an attempt to replace copper.<sup>3–5</sup> However, the astounding electrical properties of individual CNTs begin to diminish upon the creation of macroscopic CNT assemblies such as films (or buckypaper) and fibers (or wires), due to aggregation of defects, intertube contact resistance, and the misalignment of CNTs.<sup>6–9</sup> Reducing these negative effects is difficult due to the CNT's complicated synthesis conditions, hydrophobicity, large aspect ratio *etc.*, making it problematic to create homogenous dispersions in which one can align or modify individual tubes using various methods.<sup>10–13</sup> Fabricating CNT fibers with high conductivities has been studied extensively by many researchers due to the ease of effectively eliminating those drawbacks in fiber forms<sup>14–19</sup> compared to CNT films.<sup>20–23</sup> Different ways to spin CNT fibers include from

solution,<sup>24</sup> arrays,<sup>18</sup> aerogels,<sup>8</sup> and rolling CNT films.<sup>25</sup> Following fiber spinning, certain post-treatment methods are available to further increase conductivity. For instance, Liu *et al.* began with aerogel spun CNT fiber and applied a nitric acid treatment yielding a conductivity up to  $1.8 \times 10^6 \text{ S m}^{-1}$ .<sup>15</sup> Other groups used mechanical densification to reduce fiber diameter size, thereby reducing intertubular space and reducing contact resistance between the tubes.<sup>8,16,26–28</sup> Duong and co-workers reported the effectiveness of mechanical pressing to improve the conductivity to the range of  $10^6 \text{ S m}^{-1}$ .<sup>15,16,27</sup> However, translating these post-treatment processes to buckypaper is more complex due to the increased dimensions of buckypaper compared to the densely-packed, small-diameter fibers. It is challenging but highly demanding to fabricate highly conductive buckypaper for various commercial applications with the rise of portable flexible electronics such as roll-up cell phones and tablets. Using CNT thin films as conductive mediums within organic light-emitting diodes (OLEDs) has been a high possibility for this industry.<sup>29,30</sup> Therefore, it is critical that these thin films exhibit high conductivity, while still retaining performance stability and should have the ability to be mass produced.

The alignment of CNTs within a film was discovered to be an important factor for improving conductivity. Compared to the magnetic or electric field assisted method,<sup>10,31</sup> mechanical stretching has been reported to be an effective way of aligning the CNTs in films at a reasonable cost, resulting in a relatively dense-packing structure with reduced internal contact resistance.<sup>32–34</sup> But the resulting sample is usually small tapes due to the difficulty of balancing the product quality and scalability of

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handling large mechanical stretching machines. Meanwhile oxidant chemicals such as  $\text{HNO}_3$ ,  $\text{H}_2\text{SO}_4$ , and  $\text{ICl}$  etc., have been used on graphene oxide and CNTs as effective oxidizers, facilitating electron transport.<sup>35–39</sup> For instance, iodine doping has been reported to be an effective dopant for facilitating high speed charge transfer between tubes, reaching a conductivity of  $10^6 \text{ S m}^{-1}$ .<sup>24,40,41</sup> There have been reports of chemical treatments on double-walled CNT (DWCNT) films with hydrogen peroxide where they obtained conductivities of  $\sim 3.6 \times 10^5 \text{ S m}^{-1}$  at 300 K.<sup>42</sup> However, due to the highly reactive nature of oxidant chemicals, unstable electrical performance in open air is problematic. Furthermore, the capability of scalable production is a critical step for commercial applications. Currently, batch production of buckypaper has been reported extensively in literature, which falls into two basic categories: dry method and wet method. Directly spinning from CNT arrays which are first grown on a substrate is popular,<sup>43,44</sup> but the quality variance from batch to batch is difficult to control and the production capability is limited due to the small size of substrates. Although continuous buckypaper (CBP) can be obtained using the floating catalyst chemical vapor deposition method (FCCVD),<sup>20</sup> the controlled synthesis of buckypaper with good quality still needs further optimization. The wet method usually includes liquid casting and printing,<sup>45–47</sup> droplet-drying,<sup>48</sup> and vacuum filtration.<sup>49</sup> Among them, vacuum filtration is a simple and versatile method suitable for nanoscale fibrous materials. Usually it involves a single stage vacuum filtration system using a CNT suspension.<sup>49</sup> Even though large filtration system can be developed,<sup>50</sup> the lateral dimension and length of fabricated buckypaper is still limited, which makes scalable roll-to-roll manufacturing of buckypaper production difficult.

In our previous study, it has been successfully demonstrated that the integration of  $\text{I}_2$  doping and CNT alignment achieves highly conductive CNT tapes with a stable electrical conductivity of  $1.3 \times 10^6 \text{ S m}^{-1}$ .<sup>34</sup> For this study, the main focus is placed on the large-scale production of buckypaper with desirable electrical conductivity and stable performance using a fast and low-cost method. Here we reported roll-to-roll CBP that could be fabricated in a short time by an in-house-built continuous filtration process machine.<sup>22</sup> Utilizing our own CBP as a starting point, various post-treatments are investigated to improve its electrical conductivity, such as thermal treatment, nitric acid etching and oxidation, and gaseous iodine doping. The instability of the high conductivity after various post-treatments is also evaluated and is stabilized by using a polymer coating layer of poly(3,4-ethylenedioxythiophene)-poly(styrenesulfonate) (PEDOT:PSS). Most importantly, the continuous process with roll-to-roll manufacturing capability and low cost enables the CBP for large scale production, which is a critical key to its rapid development in engineering applications.

## Experimental

### Materials

Nitric acid ( $\text{HNO}_3$ ), iodine ( $\text{I}_2$ ), and poly(3,4-ethylenedioxythiophene)-poly(styrenesulfonate) (PEDOT:PSS)

were purchased from Sigma-Aldrich Inc. (St Louis, MO). Multi-walled carbon nanotube (MWCNT) powder was purchased from General Nano Inc. (Cincinnati, OH). Surfactant of Triton™ X-100 was purchased from Alfa Aesar.

### Preparation of CBP

A homogeneous aqueous CNT suspension with surfactant was obtained with the assistance of a tip sonicator (QSonica S4000) for a specific sonication time. Using this CNT suspension, the CBP was fabricated at the High-Performance Materials Institute (HPMI) following the method described elsewhere.<sup>22,51</sup> Briefly, the roll-to-roll manufacturing system was built, and comprised of a suspension tank of CNTs, and a filtration unit. The tank can continuously feed CNT suspension to the filtration unit, which is made of (i) a suspension chamber in fluid supplied from the suspension tank, (ii) a filter paper associated with two or more pinch rollers for continuous feeding, (iii) a filtration area associated with a vacuum pump, (iv) a drying area, and (v) a roll for collecting the CBP. The scalability of CBP roll-to-roll manufacturing makes it a promising raw material for a wide range of engineering applications. Raw CBP was used as prepared. The remaining surfactant was removed through a heat treatment in a box furnace at 400 °C for 3 hours with ambient atmosphere. These heated samples were directly used for the following chemical doping processes. Heat treated BP was soaked in 5 M  $\text{HNO}_3$  for 5 minutes. Then the samples were rinsed with de-ionized water and dried in an oven at 70 °C in air. After the acid treatment, additional iodine doping was conducted in a sealed glass container which housed iodine solid crystals and the  $\text{HNO}_3$  treated CBP together. The container was placed in an oven at 70 °C for two hours while the iodine sublimed and doped the sample.<sup>34</sup> Also, exclusively iodine doped CBP after the heat treatment, following the same method above, was prepared as a control to investigate the synergistic effect of  $\text{HNO}_3$  and  $\text{I}_2$  on the electrical conductivity. The conductive polymer PEDOT:PSS was used as received without any dilution. It was coated on the surface of the doped CBP by a simple dip-coating method and dried at room temperature overnight. This simple and effective post-treatment, plus the roll-to-roll scalability of the CBP manufacturing could shed light on the capability of large-scale production and potentially broaden the applications of conductive CNT films.

### Characterizations

Electrical property measurements were conducted using a current source (Keithley 6221) and nanovoltmeter (Keithley 2182A) with the four-probe configuration stage (JANDEL Universal Probe). Resistivity ( $\rho$ ) was calculated from the slope of the  $I$ - $V$  curve based on the equation:

$$\rho = \frac{\pi t}{\ln 2} \frac{V}{I} = 4.53t \frac{V}{I}$$

where  $t$  is the sample thickness;  $V$  and  $I$  is the voltage and the current, respectively. Scanning electronic microscopy (SEM, JSM-7401F, JEOL.) was used for morphology analysis. Raman analysis was completed by a Renishaw inVia micro-Raman



system using a 785 nm excitation wavelength. Thermogravimetric analysis (TGA) was conducted using the Q50 (TA Instrument Inc.) with a  $10\text{ }^{\circ}\text{C min}^{-1}$  rate from  $50\text{--}850\text{ }^{\circ}\text{C}$  in air and nitrogen.

## Results and discussion

### Fabrication of highly conductive CBP

The CBP was fabricated by following the scale-up production method described in our previous work and patent.<sup>22,51</sup> The roll-to-roll product from continuous process is as shown in Fig. 1a. Depending on the adjustable apparatus used in the continuous manufacturing process, CBP with a width of 6 or 12 inches was obtained. The post-treatments to improve the electrical conductivity of CBP is schematically depicted in Fig. 1b–e. Fig. 1b shows the raw CBP containing surfactant, which is insulating and detrimental to electron transfer. In this study, heat treatment was used to efficiently remove the remaining surfactant introduced in the CBP manufacturing process. A clean CBP could be obtained as shown in Fig. 1c, marked as heated CBP. To achieve even higher conductivity, chemical doping with nitric acid ( $\text{HNO}_3$ ) and iodine ( $\text{I}_2$ ) was performed and marked as  $\text{HNO}_3$  CBP, and  $\text{I}_2$  CBP, respectively.  $\text{HNO}_3/\text{I}_2$  CBP represents the sample with the combination of  $\text{HNO}_3$  and  $\text{I}_2$  treatments. These dopants, as shown in Fig. 1d, could improve the electron transfer efficiency,<sup>52</sup> resulting in a highly conductive CNT network. Lastly, a protective layer of conductive polymer (*i.e.* PEDOT:PSS) (Fig. 1e) was coated on the chemically doped CBP to stabilize the high electrical performance, which

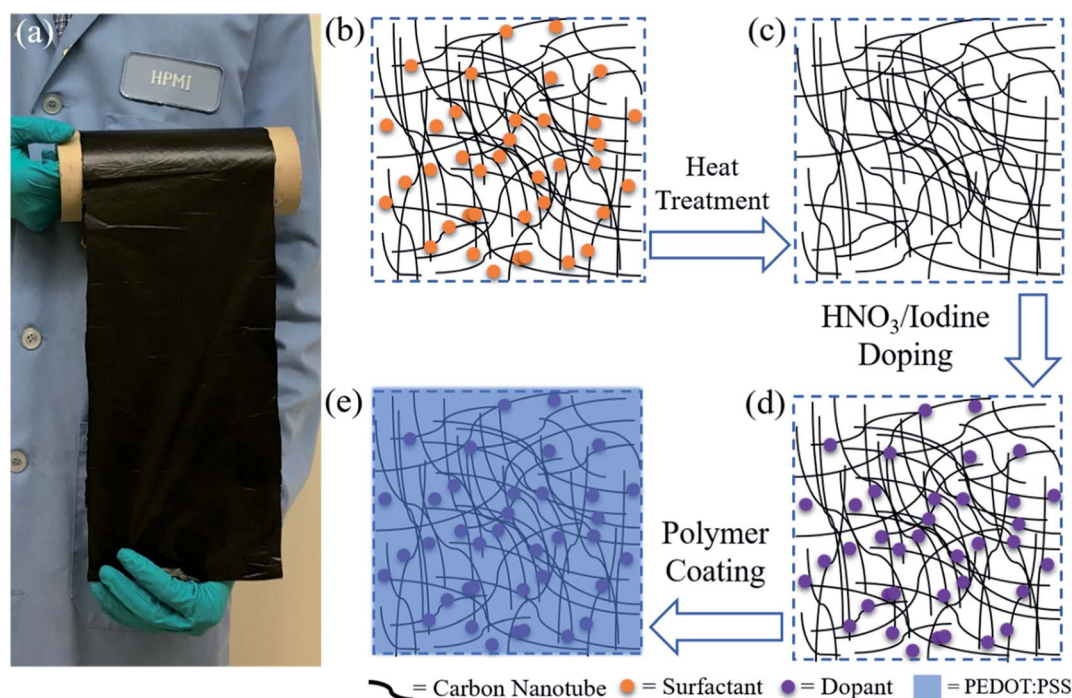
was pivotal in achieving long-term favorable electrical properties. The chemically doped CBP was characterized by Raman spectroscopy, SEM, and TGA. Also, the long-term stability of high conductivity was investigated by constantly checking the conductivity variance over time.

### Morphology characteristics of CBPs after different treatments

The scanning electron microscopic images of the CBP before and after heat treatment are shown in Fig. 2a and b. A homogeneous CNT bundle network of raw (Fig. 2a) and heated (Fig. 2b) CBP are observed. The randomly ordered CNT network and entanglement are preserved following the heat treatment. Under the heat treatment condition applied in this study ( $400\text{ }^{\circ}\text{C}$  for 3 hours), the heated CBP should be free of surfactant due to the low decomposition temperature of Triton<sup>TM</sup> X-100 at  $280\text{--}350\text{ }^{\circ}\text{C}$ , and extended treatment time (3 hours). The resulting heated CBP still shows structural integrity (Fig. 2b), implying the success of heat treatment leading to surfactant removal without structural damages (more details of surfactant removal analysis will be discussed in the TGA data). Moreover,  $\text{HNO}_3$  and  $\text{I}_2$  doping did not deteriorate the CNT structure, as shown in Fig. 2c and d. The combination of  $\text{HNO}_3$  and  $\text{I}_2$  treatment was also demonstrated to show no negative effect on CNT structural integrity (Fig. 2e).

### Doping quality characterization

Raman spectroscopy is widely used to characterize the structure of CNTs in terms of the different bonding types of  $\text{sp}^2$  and  $\text{sp}^3$  hybridized carbon atoms. The D band (disorder-induced mode),



**Fig. 1** Scalable doping of roll-to-roll continuous buckypaper (CBP): (a) digital image of CBP manufactured at HPML. (b)–(e) Schematic illustration of different post-treatments: (b) raw CBP as produced with Triton<sup>TM</sup> X-100 surfactant; (c) heat treated CBP without surfactant; (d)  $\text{HNO}_3$  and/or iodine doped CBP; (e) chemical doped CBP with PEDOT:PSS coating layer.





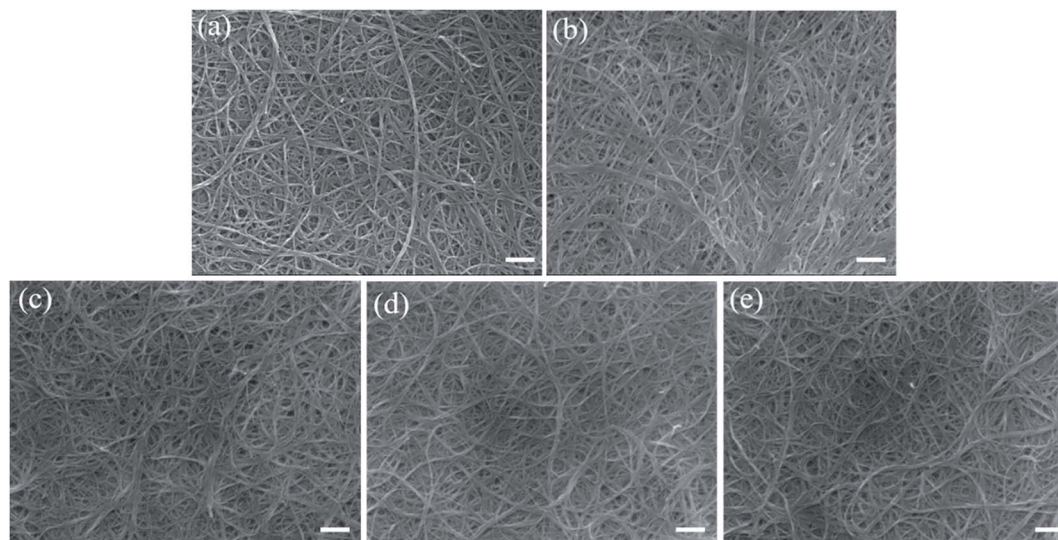


Fig. 2 Surface morphology of CBP after different post-treatments from SEM images. (a) Raw CBP; (b) heated CBP; (c)  $\text{HNO}_3$  CBP; (d)  $\text{I}_2$  CBP; (e)  $\text{HNO}_3/\text{I}_2$  CBP. Scale bar in each picture is 200 nm.

which ordinarily shows the number of defects in CNTs,<sup>37</sup> occurred at approximately  $1308\text{ cm}^{-1}$  for raw CBP as marked in Fig. 3. Another characteristic peak is the G band, an intrinsic feature of all  $\text{sp}^2$  carbons,<sup>11</sup> appeared at  $1601\text{ cm}^{-1}$  for raw CBP. A powerful indicator to describe the electronic structure of different bonding types in CNTs after various post-treatments is the intensity ratio of  $I_D/I_G$ : a higher value implies that more defects are present in the CNTs. Fig. 3 shows the characteristic D and G bands for the raw CBP and its counterparts after various post-treatments. It is interesting to note that after various post-treatments, all D band positions remained similar to that of raw CBP, but  $I_D/I_G$  changed accordingly, as listed in Table 1. A potential explanation for why there is a slightly lower  $I_D/I_G$  ratio for heated CBP (1.22) as compared to that of raw CBP (1.26) may originate from the removal of surfactant, amorphous carbon and other impurities, which may serve as a defect source for the CNT network.<sup>37</sup> After  $\text{HNO}_3$  treatment, potential oxygen-containing functional groups (structural defects) may be introduced to the side walls of CNTs,<sup>52</sup> resulting in an increase of  $I_D/I_G$  from 1.22 to 1.41. Iodine is an oxidant chemical, but the  $I_D/I_G$  only increased to 1.27, much smaller than that of  $\text{HNO}_3$  treated CBP. It was reported that the iodine doping of CNTs is mainly through physical adsorption which does not create defects.<sup>53</sup> But the slight increase of the  $I_D/I_G$  ratio could be ascribed to the possible presence of C–I bonding, which was also reported by Zhao *et al.*<sup>40</sup> The combined treatment of  $\text{HNO}_3$  and  $\text{I}_2$  showed a reasonable value of  $I_D/I_G = 1.43$ .

Compared to the G band of raw and heated CBP, which is similar at  $1601\text{ cm}^{-1}$ , a red shift of 3 to  $5\text{ cm}^{-1}$  was observed for the samples either doped by  $\text{HNO}_3$  (*i.e.*  $1604\text{ cm}^{-1}$ ),  $\text{I}_2$  (*i.e.*  $1605\text{ cm}^{-1}$ ), or the combination of both (*i.e.*  $1606\text{ cm}^{-1}$ ). This shift was attributed to the charge transfer between CNT and dopant,<sup>37,41</sup> with a larger shift implying a higher doping level. Another characteristic peak at around  $155\text{ cm}^{-1}$  was observed for the samples doped by iodine and the combination of  $\text{HNO}_3$

and iodine, respectively, as shown in Fig. 3. This unique peak did not appear in other samples (*i.e.* raw CBP, heated CBP, or  $\text{HNO}_3$  doped CBP). This new peak could be explained by the iodine anion formation of triiodide ( $\text{I}_3^-$ ) and/or pentaide ( $\text{I}_5^-$ ).<sup>41,53</sup>

TGA results, as shown in Fig. 4, were also used to investigate the effect of surfactant removal by heat treatment and the dopant quantities of  $\text{HNO}_3$  and  $\text{I}_2$ . The sample was heated up to  $850^\circ\text{C}$  in air. The black line shows the TGA profile of raw CBP, which has two decomposition stages. The first decomposition

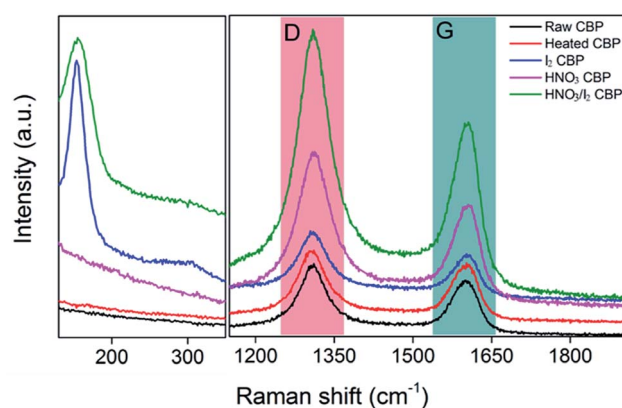


Fig. 3 Raman spectroscopy of CBP after different post-treatments with D and G band marked as colored area.

Table 1 The intensity ratio of  $I_D/I_G$  from Raman spectroscopy of CBP after various post-treatments

	Raw CBP	Heated CBP	$\text{HNO}_3$ CBP	$\text{I}_2$ CBP	$\text{HNO}_3/\text{I}_2$ CBP
$I_D/I_G$	1.26	1.22	1.41	1.27	1.43



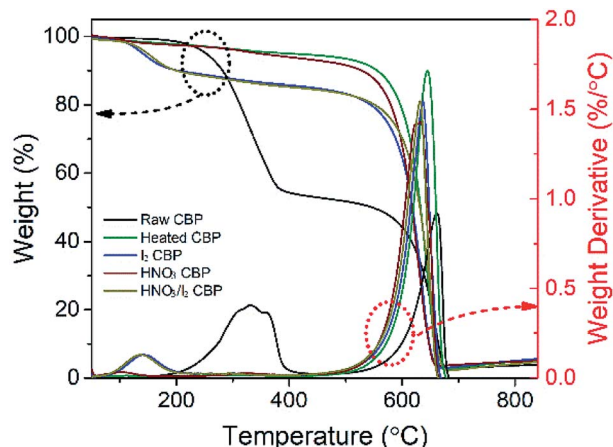


Fig. 4 The TGA and the differential TGA curve of raw CBP and the samples after different post-treatments. The heating rate was  $10\text{ }^{\circ}\text{C min}^{-1}$  from  $50\text{--}850\text{ }^{\circ}\text{C}$  under air condition.

stage with a weight loss of 42%, occurring at around  $200\text{--}400\text{ }^{\circ}\text{C}$ , mainly corresponded to the loss of surfactant of Triton<sup>TM</sup> X-100. The second decomposition stage occurred at approximately  $550\text{--}680\text{ }^{\circ}\text{C}$ , with a weight loss of around 51%, and was attributed to the decomposition of CNTs.<sup>34</sup> These two decomposition stages showed two decomposition temperature peaks at  $330\text{ }^{\circ}\text{C}$  and  $661\text{ }^{\circ}\text{C}$ , which could be observed from the corresponding differential TGA curve. Obviously, only one decomposition peak (at around  $644\text{ }^{\circ}\text{C}$ ) was observed in the TGA curves of heated CBP (green curve), indicating the effectiveness of heat-treatment induced surfactant removal. Similarly, the  $\text{HNO}_3$  treated CBP showed only a CNT decomposition stage. It is important to note that there is a slight difference in weight variance (*i.e.* 2–3%) in the temperature range of less than  $600\text{ }^{\circ}\text{C}$  between heated and  $\text{HNO}_3$  treated CBP, which may be explained by the loss of oxygen-containing functional groups induced by  $\text{HNO}_3$ . The iodine doped CBP showed a new decomposition stage in addition to the CNT decomposition stage. The weight loss of 9.4% could be attributed the decomposition of iodine, which showed a decomposition temperature peak at  $143\text{ }^{\circ}\text{C}$ . No new peaks were observed for the combination of  $\text{HNO}_3$  and  $\text{I}_2$  doped sample.

### Electrical performance improvement by chemical doping

To understand the effect of surfactant removal and the dopant functionalization of  $\text{HNO}_3$  and  $\text{I}_2$ , and the combination of them, the electrical properties of the samples were measured using a four-probe configuration. The measured electrical conductivity of the raw CBP was around  $1.3 \times 10^4\text{ S m}^{-1}$ , as seen in Fig. 5. After surfactant removal by heat treatment, the conductivity increased to approximately  $1.6 \times 10^4\text{ S m}^{-1}$ . Both  $\text{HNO}_3$  and  $\text{I}_2$  could significantly increase the conductivity to  $3.8 \times 10^4\text{ S m}^{-1}$ , and  $4.4 \times 10^4\text{ S m}^{-1}$ , respectively. Compared to  $\text{HNO}_3$  and  $\text{I}_2$  exclusively doped CBP cases, the effect of the combined  $\text{HNO}_3$  and  $\text{I}_2$  treatment on the electrical conductivity was more significant and the resulting conductivity increased up to  $7.6 \times 10^4\text{ S m}^{-1}$ , nearly 6 times higher than that of raw CBP.

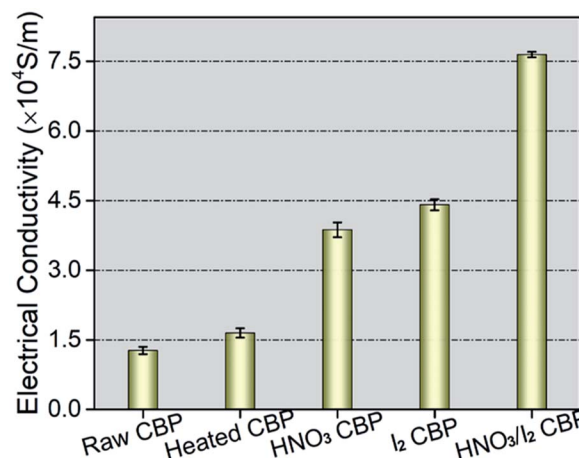


Fig. 5 Electrical conductivity of raw CBPs and the ones with different post-treatments.

The mechanism of such a high improvement in electrical conductivity after  $\text{HNO}_3$  and  $\text{I}_2$  doping could directly result from the improved charge carrier concentration and its mobility.<sup>24,40</sup> As oxidant chemicals,  $\text{HNO}_3$  or  $\text{I}_2$  showed the capability of withdrawing electrons from CNTs.<sup>41</sup> Consequently, holes (electron deficiencies) could be created, which accelerate the neighboring hole mobility to reach an electronic equilibrium status.<sup>54</sup> Based on the hole concentration and mobility, the electrical conductivity ( $\sigma$ ) is defined by:

$$\sigma = ne\mu$$

where  $n$  is the hole concentration,  $e$  is the electron charge, and  $\mu$  is the hole mobility. After chemical doping, the hole concentration could be increased due to the strong electron-withdrawing capability of oxidant dopant of  $\text{HNO}_3$  and  $\text{I}_2$ , with a concomitant increase in hole mobility. As a result, a higher electrical conductivity of doped samples was expected, as shown in Fig. 5, compared to the raw and heated counterparts. Another possible reason for the high electrical conductivity could be ascribed to the improved contact conductance between tubes and bundles, benefitting from the bridge effect of dopants located at the contact area, which served as a conductance pathway.<sup>12</sup>

The electron transfer mechanism for raw CBP and the post-treated samples are schematically illustrated in Fig. 6. The surfactant (*i.e.* Triton<sup>TM</sup> X-100), either wrapping around the tubes or accumulating at the contact areas between tubes, could hinder the electron transport along tubes or across neighboring tubes (Fig. 6a) due to its non-conductive nature, resulting in a relatively high resistance (low conductance). Surfactant removal improved the efficiency of electron transfer between and along the tubes (Fig. 6b), which was verified by the minor improvement in the electrical conductivity (Fig. 5). When it comes to the further improvement in conductivity of the  $\text{HNO}_3$  and  $\text{I}_2$  treated CBP, fast hole mobility may be the explanation, which is also reported by others.<sup>38,39</sup> These oxidant chemicals, acting as electron-withdrawing sites (electron acceptors), could create holes (p-



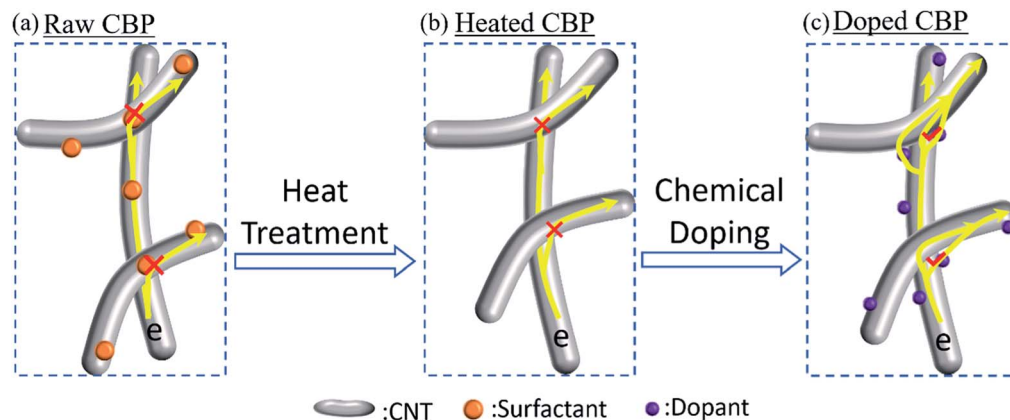


Fig. 6 Schematic drawing to illustrate the electron transfer efficiency after different post-treatments. Raw CBP with surfactant (a) after heat treatment (b) and chemical doping (c). Contact resistance was expected to be reduced significantly with reduced contact resistance and additional transport path.

type doping).<sup>39,55</sup> Once the hole concentration increased (*i.e.* created by oxidant dopant of  $\text{HNO}_3$  and  $\text{I}_2$ ), a much higher electron transfer efficiency along tubes may be expected compared to raw CBP. Additionally, due to the possible electron conduction pathway established in the charge-transfer complex between neighboring tubes, an enhanced electron transfer across different tubes may also contribute to the improved electrical conductivity as shown in Fig. 6c.<sup>55</sup>

#### Improved stability of highly conductive CBP by PEDOT:PSS

There is a major concern for CBP with high electrical conductivity in long-term performance stability. Although doping with  $\text{HNO}_3$  and  $\text{I}_2$  could achieve high electrical conductivity, other researchers also reported the instability of the doping effect.<sup>53,54</sup> In this study, we first investigated the thermal stability of  $\text{HNO}_3/\text{I}_2$  CBP. In Fig. 7a, the results of TGA data carried out in both an air and nitrogen atmosphere showed the same degradation

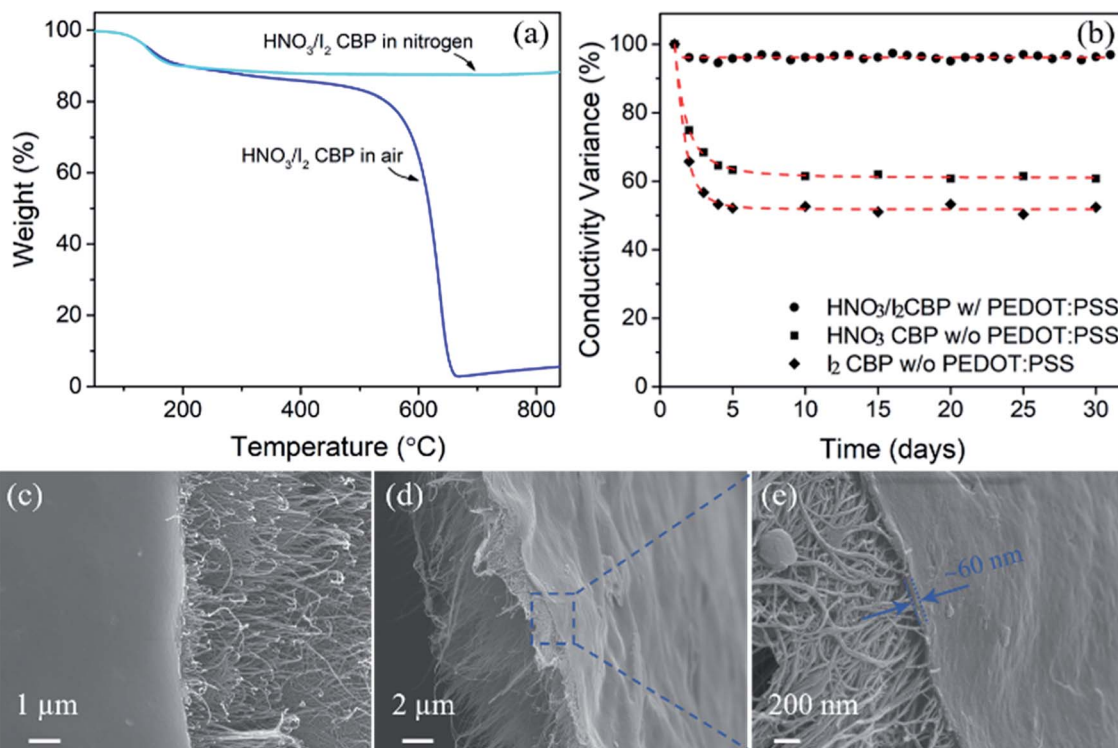


Fig. 7 (a) TGA data of  $\text{HNO}_3/\text{I}_2$  CBP carried in both an air and nitrogen atmospheres. (b) Open air stability of chemically doped CBPs with and without a PEDOT:PSS coating layer. The highly conductive performance of  $\text{HNO}_3/\text{I}_2$  CBP w/PEDOT:PSS is stable for more than a month in open air with a relative 3–5% variance. Red dashed line is shown as a guide to the eyes. (c–d) SEM images of PEDOT:PSS coating layer on the surface of CBP: (c) CBP with coating (left) and without coating (right), (d) a fracture and (e) high magnification of dash-line box area in (d).





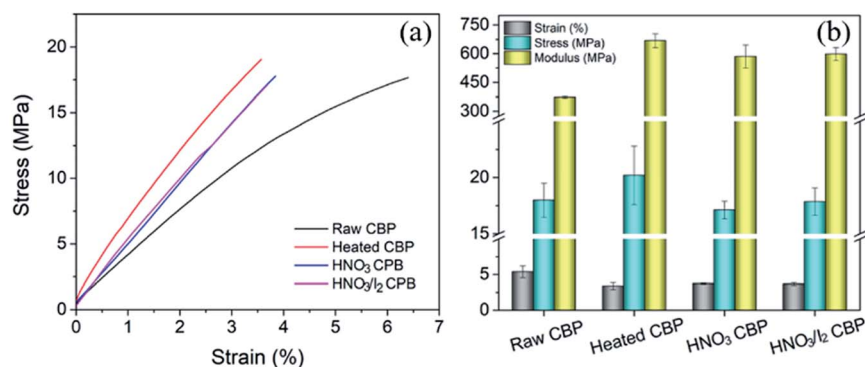


Fig. 8 (a) The mechanical properties of CBP after various post treatments. (b) Tensile strength, failure strain and tensile modulus extracted from the curves in (a).

peak at  $\sim 143^\circ\text{C}$ , which was attributed to the loss of iodine. This is consistent with the common knowledge that iodine can sublime even at room temperature. In addition, in terms of electrical conductivity as shown in Fig. 7b, nearly a 40% and 50% decrease was observed from HNO<sub>3</sub> and I<sub>2</sub> doped CBP, respectively. It is critical to achieve long-term stability for potential engineering applications. In this study, the conductive polymer PEDOT:PSS was used as a protective coating layer to maintain the highly conductive performance of CBP doped by the combination of HNO<sub>3</sub> and I<sub>2</sub>. After a simple dip-coating method, the PEDOT:PSS coated HNO<sub>3</sub>/I<sub>2</sub> CBP was dried at room temperature. It is interesting to note that only a small conductivity variance (3–5%) appeared for a testing period of more than a month. After studying the surface morphology of the polymer coated CBP, as shown in Fig. 7c, it is possible that the uniform coating layer prohibits the sublimation of iodine and other potential reactions between chemical dopants and air. From the fracture morphology (Fig. 7d and e) of the polymer coated CBP, we can clearly see that the PEDOT:PSS layer is only on the surface of the CBP with a thickness of around 60 nm. The anti-conductivity-degradation of chemical doping using a polymer coating layer was also found in other papers.<sup>54</sup> While the mechanism of the interaction between PEDOT:PSS and doped CNT is not well understood, it is obvious to conclude that the coating layer of a conductive polymer could significantly improve the stability of CBP high conductivity as shown in Fig. 7 (black circle dot). We believe that such a dramatic improvement in stability, along with the high electrical conductivity and large-scale production capability, could make the HNO<sub>3</sub> and I<sub>2</sub> doped CBP a promising candidate for wide engineering applications including lightweight conductive tapes, electrodes, and lightweight strike protection shield *etc.*

### Mechanical properties of CBP

The stress-strain curves for the CBP after various post-treatments are plotted in Fig. 8a. After heat treatment, both tensile strength and modulus increased, while decreased failure strain was observed. The surfactant molecules could serve as cross-linkers between neighboring CNTs. Surfactants may lubricate CNTs during tensile test, leading to a higher failure

strain, as compared to that of CBP after surfactant removal.<sup>10</sup> Although, after chemical doping by HNO<sub>3</sub> and I<sub>2</sub>, a small decrease in mechanical properties was observed, no deterioration of mechanical strength appeared for any of the post-treated samples.

## Conclusion

We have demonstrated an effective chemical doping method that uses oxidant dopant (*i.e.* HNO<sub>3</sub> and I<sub>2</sub>) to increase the hole concentration and mobility to produce a high electrically conductive CBP. In combination with the scalable roll-to-roll CBP manufacturing process, chemical doping induced high electrical conductivity. Furthermore, long-term performance stability was assisted and achieved by a conductive polymer coating layer of PEDOT:PSS. This scale-up manufacturing effort produces highly conductive CBP materials that can enable engineering applications, such as cabling, EMI shielding, flexible electronics, or electrodes for energy storage devices.

## Conflicts of interest

There are no conflicts to declare.

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